



200V 3A Schottky Diode - SiS60T200S

Silicon Schottky Rectifier in bare die form

Version 1.0
06/04/18

Applications

- Switching Power Supply
- Converters
- Free Wheeling Diodes

Features

- Ultra Low Reverse Current
- Soft recovery low & high temperature
- Low forward Voltage drop

Electrical Characteristics

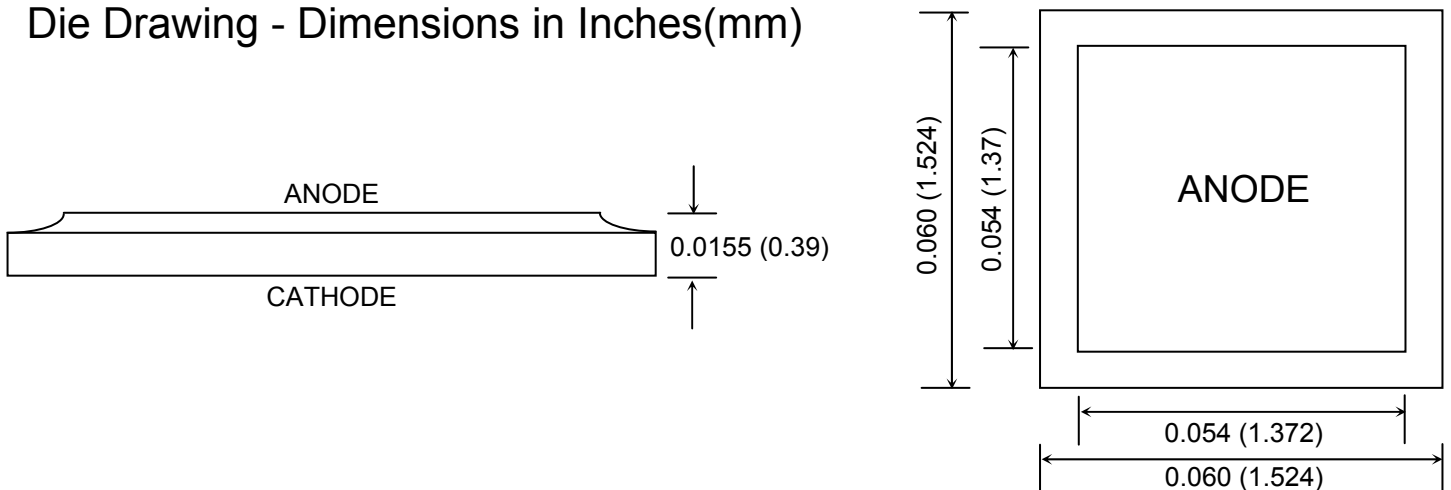
Symbol	Parameter	Conditions	Typ	Max	Unit
V_R	Reverse Voltage	-	-	200	V
I_R	Reverse Current	$V_R = 200V, T_J = 25^\circ C$	-	0.07	mA
		$^1V_R = 200V, T_J = 125^\circ C$	-	1.6	mA
V_F	Forward Voltage	$I_F = 3A @ 25^\circ C$	-	0.92	V
T_J	Junction Temperature	-	-	200	$^\circ C$

Note 1: Not production tested at wafer level, tested in package

Mechanical Data

Die Attach Method	Front Metal Composition			Back Metal Composition		
Solderable Top Solderable Back	-	TiNiAg 30kÅ	-	Ti	Ni	Ag 30kÅ

Die Drawing - Dimensions in Inches(mm)



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